

Towards a THz room-temperature integrated parametric source



G. Leo

Laboratoire MPQ
Univ. Paris Diderot (France)
+33 (0)1 57 27 62 27
giuseppe.leo@univ-paris-diderot.fr

J.M. Gérard

CEA-CNRS
Grenoble (France)
+33 (0)4 38 78 31 34
jean-michel.gerard@cea.fr

S. Reitzenstein

Physik. Institut
Univ. Würzburg (Germany)
+49 (0)931 31 85 116
stephan.reitzenstein@physik.uni-wuerzburg.de

P.U. Jepsen

Dept. of Photonics Eng.
Technical Univ. of Denmark
+45 45 25 57 11
puje@fotonik.dtu.dk

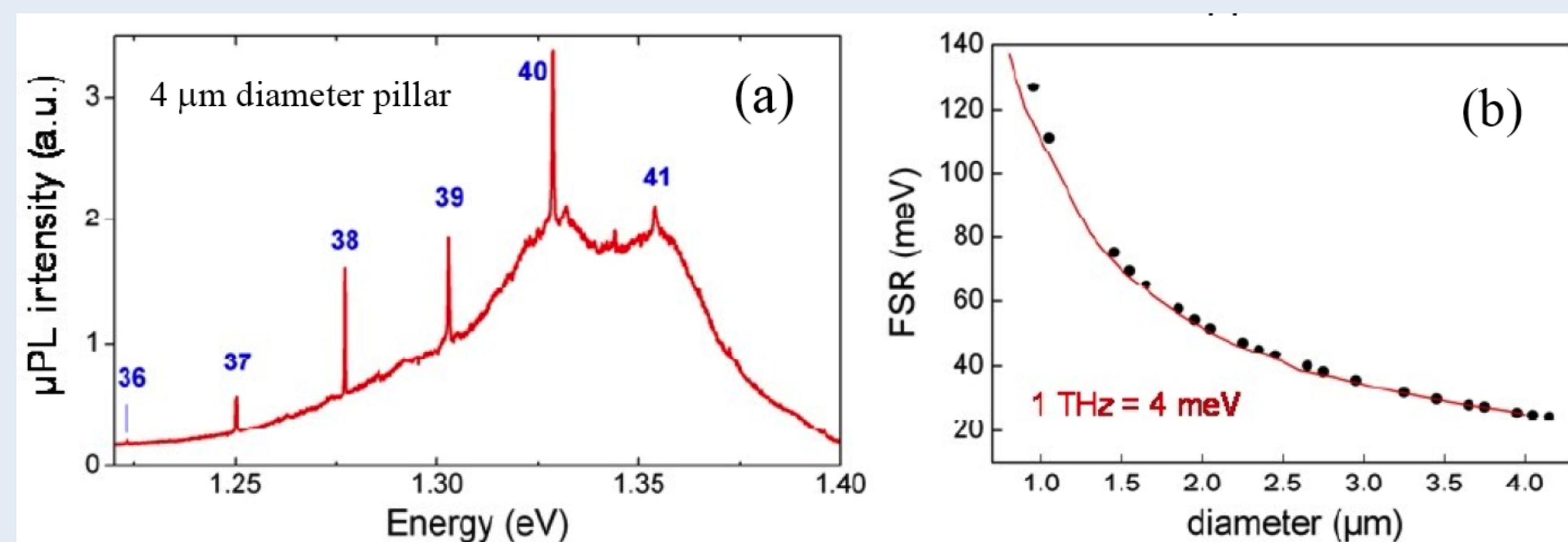
MOTIVATION

We aim at demonstrating a radically new continuous-wave, electrically pumped terahertz emitter. Compared to existing THz sources, this source will bring together several crucial advantages that are far from being simultaneously available in any existing source today: compact size, room-temperature operation, output power above 1 μ W, custom emission frequency from 2.4 to 6 THz, spectral purity, feasibility of multi-spectral array of emitters, and perspective of coherent detection schemes.

FORMER OBSERVATION (Grenoble, 2007)

Photo-luminescence of GaAs/AlAs micropillars containing InAs quantum dots (QDs) is dominated by one family of horizontally polarized, near-IR, high-Q whispering gallery modes (WGMs). [1]

- nanofabrication by MBE, e-beam lithography and RIE
- high Q-factor WGMs (diam. 4 μ m, $Q > 10^4$)
- stable multi-mode lasing
- no gain competition (QD active medium)
- better heat-sinking than in microdisks
- THz free spectral range (FSR) for sufficiently large diameters



WGMs in a micropillar, from Ref. [1]: measured spectrum (a) and FSR (b).

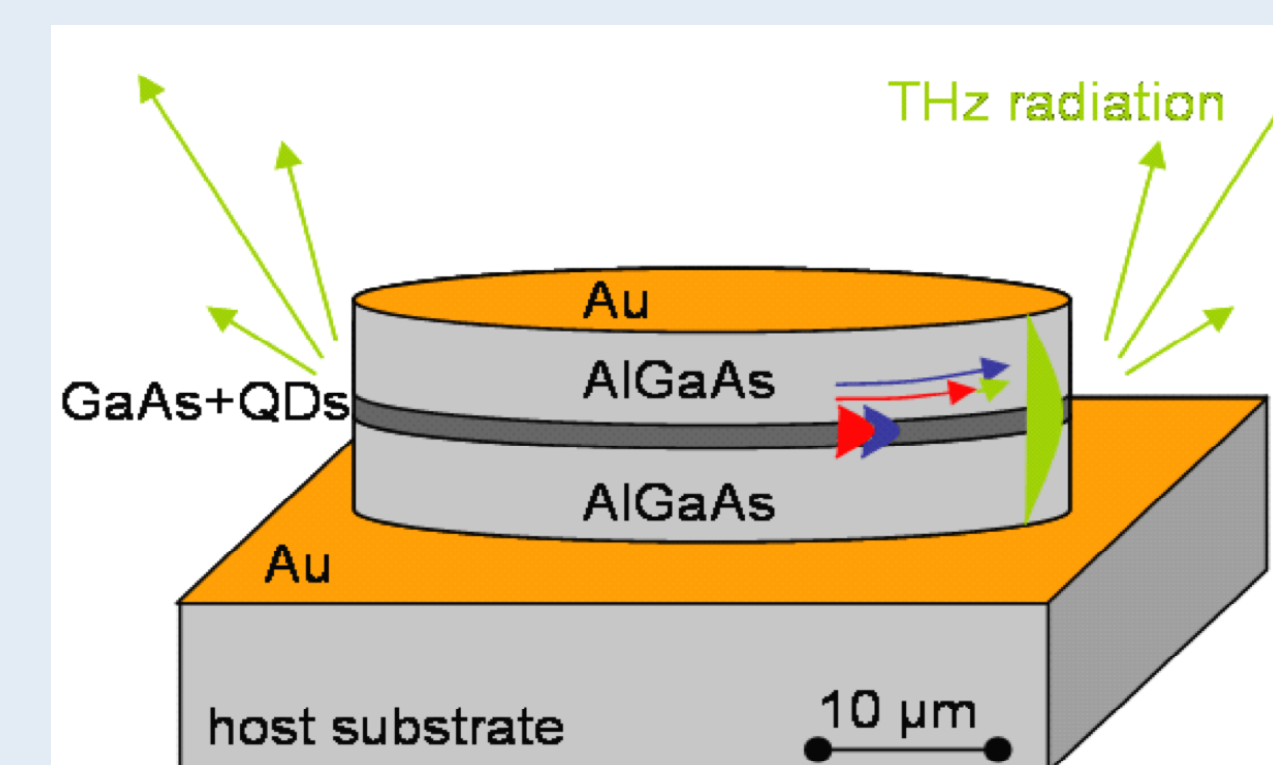
CONTEXT

In 2008 Capasso's group at Harvard has proposed a THz source based on DFG in a dual- λ mid-IR QCL. [2] Due to heavy doping, its performance is limited by free-carrier absorption (FCA) in the THz, and it can only emit pulses of a few hundreds of nW at 300 K.

THE IDEA BEHIND THE PROJECT (Paris, 2008)

DFG in an AlGaAs active whispering gallery resonator (WGR). [3] Vertical confinement of the optical field provided by dielectric or plasmon-enhanced guiding. In the horizontal plane, guidance granted by the bent semiconductor/air interface. Performance measured in terms of Q factor and FSR.

Two phase-matching schemes for THz DFG in WGRs fabricated on (100)-GaAs: 1) anomalous dispersion related to the phonon absorption band; 2) QPM associated to the azimuthal modulation of the effective $\chi^{(2)}$. [4]



The TREASURE device

THE TREASURE PROJECT (May 2010 – April 2013)

During the first year of the project, we have:

1. demonstrated lasing in QD WGRs, in the CW regime at 100 K, under optical pumping [5], as well as electrical pumping at 10 K; [6]
2. progressed in the modeling of the laser heterostructure (composition profile and doping), the linear and nonlinear behavior of near-IR and THz WGMs, as well as the radiating features of the THz emitter; [7]
3. fabricated and tested the experimental setup for the linear and nonlinear optical characterization of passive and active WGRs. [8, 9]

REFERENCES

1. Y.-R. Nowicki-Bringuier et al., Opt. Expr. 15, 17291 (2007).
2. M. A. Belkin et al., Appl. Phys. Lett. 92, 201101 (2008).
3. A. Andronico et al., Opt. Lett. 21, 2416 (2008).
4. Y. Dumeige and P. Féron, Phys. Rev. A 74, 063804 (2006).
5. P. Jaffrennou, Appl. Phys. Lett. 96, 071103 (2010).
6. F. Albert et al., Appl. Phys. Lett. 97, 101108 (2010).
7. F. Eichhorn et al., Paper Mo-C2.4, IRMMW 2010, Rome, Italy, 5-9/9 (2010).
8. L. Ding et al., Appl. Opt. 49, 2441 (2010).
9. L. Ding et al., Phys. Rev. Lett. 105, 263903 (2010).

CONCLUSION AND PERSPECTIVES

Most relevant result of TREASURE's first year:

- Demonstration of lasing in QD WGRs under electrical pumping.

Main issues in the next semester:

- Confirm via fully vectorial FDTD the effective-index predictions of THz DFG between 2.4 and 6 THz, in the microwatt range.
- Characterize the first WGR samples.
- Achieve the lasing of optically pumped WGRs at 300K.
- Achieve low-threshold lasing in electrically-pumped WGRs.

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TREASURE

